

Automotive IPD Series

2ch High Side Switch

BV2HM050EFV-C

General Description

BV2HM050EFV-C is a 2ch high side switch for automotive application. It has a built in hiccup mode overcurrent protection function, thermal shutdown protection function, open load detection function, under voltage lockout function. It is equipped with diagnostic output function for abnormality detection.

Features

- AEC-Q100 Qualified(Note 1)
- Built in Hiccup Mode Overcurrent Protection Function (OCP)
- Built-in Thermal Shutdown Protection Function (TSD)
- Built-in Open Load Detection Function (OLD)
- Built-in Under Voltage Lockout Function (UVLO)
- Low On-Resistance $R_{ON} = 50 \text{ m}\Omega$ (Typ)
- Monolithic Power Management IC with the Control Block (CMOS) and Power MOSFET Mounted on a Single Chip

(Note 1) Grade1

Application

 Resistance Load, Inductance Load and Capacitance Load for Automotive Application

Key Specifications

Power Supply Voltage Operating Range: 6 V to 28 V
 ON-Resistance (Tj = 25 °C): 50 mΩ (Typ)
 Overcurrent Value: 5 A (Min)
 Standby Current (Tj = 25 °C): 0.5 μA (Max)

■ Active Clamp Energy (Tj = 25 °C):

Package HTSSOP-B20 W (Typ) x D (Typ) x H (Max) 6.5 mm x 6.4 mm x 1.0 mm

140 mJ



HTSSOP-B20

Typical Application Circuit

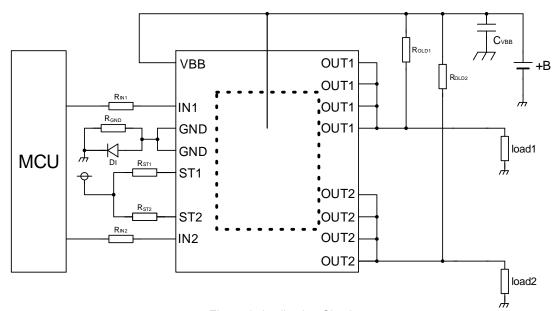


Figure 1. Application Circuit

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Pin Configuration

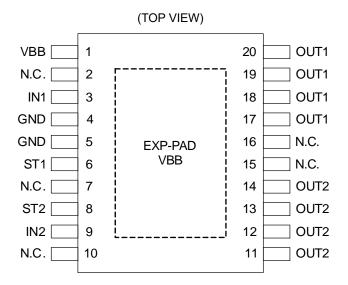


Figure 2. Pin Configuration

Pin Description

Description		
Pin No.	Pin Name	Function
1	VBB	Power input pin, switch input pin
2	N.C.	-
3	IN1	Channel 1 Input pin. Pull-down resistor is connected internally.
4	GND	Ground pin
5	GND	Ground pin
6	ST1	Channel 1 Self-diagnostic output pin
7	N.C.	-
8	ST2	Channel 2 Self-diagnostic output pin
9	IN2	Channel 2 Input pin. Pull-down resistor is connected internally.
10	N.C.	-
11 to 14	OUT2	Channel 2 Switch output pin
15	N.C.	-
16	N.C.	-
17 to 20	OUT1	Channel 1 Switch output pin
EXP-PAD	VBB	Power input pin, switch input pin

Block Diagram

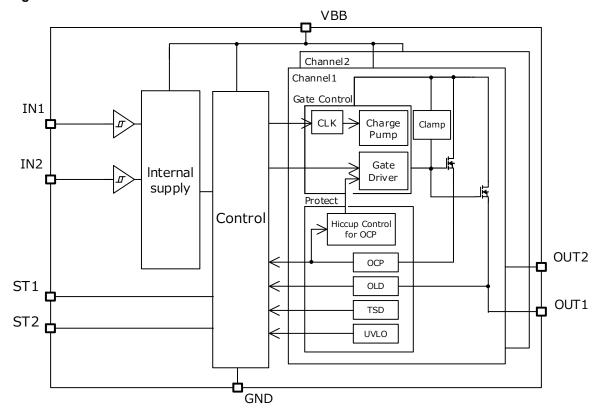


Figure 3. Block Diagram

Definition

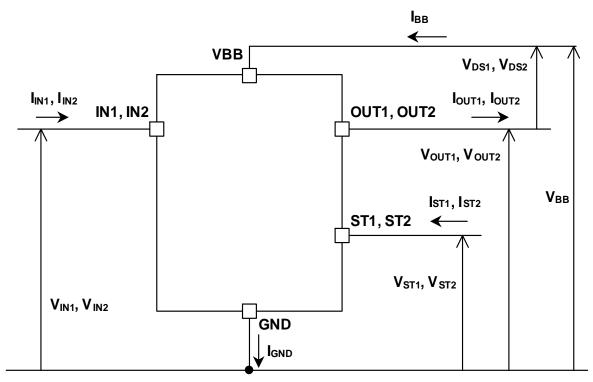


Figure 4. Voltage and Current Definition

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
VBB - OUT Voltage	V _{DS}	-0.3 to Internal clamp ^(Note 1)	V
Power Supply Voltage	V _{BB}	-0.3 to +40	V
Input Voltage	V _{IN1} , V _{IN2}	-0.3 to +7.0	V
Input Current	I _{IN1} , I _{IN2}	-2.0 to +2.0	mA
Diagnostic Output Voltage	V _{ST1} , V _{ST2}	-0.3 to +7.0	V
Output Current	Iout1, Iout2	11.0 (Overcurrent Value I _{OC}) ^(Note 2)	Α
Junction Temperature Width	Tj	-40 to +150	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C
Active Clamp Energy ^(Note 3) (Note 4) (Single Pulse, Tj = 25 °C)	Eas	140	mJ
Active Clamp Energy ^(Note 3) (Note 4) (Single Pulse, Tj = 150 °C)	Eas	65	mJ
Supply Voltage for Short Circuit Protection (Note 4) (Note 5)	V _{BBLIM}	28	V

(Note 1) Internally limited by output clamp voltage.

(Note 2) When overcurrent flows, output is turned off. (Output self-restarts after a certain time.)

(Note 3) Maximum active clamp energy using Single Pulse of $I_{OUT(START)} = 2 A$ and $V_{BB} = 14 V$.

(Note 4) Not 100 % tested.

(Note 5) Maximum power supply voltage that can detect short circuit protection.

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Caution 3: When IC turns off with an inductive load, reverse energy is generated. This energy can be calculated by the following equation:

$$E_L = \frac{1}{2} \times L \times I_{OUT(START)}^2 \times \left(1 - \frac{V_{BB}}{V_{BR} - V_{DS}}\right)$$

Where:

L is the inductance of the inductive load.

 $I_{OUT(START)}$ is the output current at the time of turning off.

The BV2HM050EFV-C integrates the active clamp function to internally absorb the reverse energy E_L which is generated when the inductive load is turned off. When the active clamp operates, the thermal shutdown function does not work. Decide a load so that the reverse energy E_L is active clamp energy E_A s (refer to Figure 5. Active Clamp Energy vs Output Current) or under when inductive load is used.

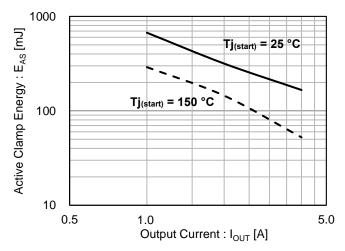


Figure 5. Active Clamp Energy vs Output Current

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Operating Power Supply Voltage	V _{BB}	6	14	28	V
Operating Temperature	Topr	-40	+25	+150	°C
Operating Frequency (Input Voltage 50 % Duty)	fin	-	-	1	kHz

Thermal Resistance^(Note 1)

Parameter	Symbol	Тур	Unit	Condition
HTSSOP-B20				
		108.1	°C/W	1s ^(Note 2)
Between Junction and Surroundings Temperature Thermal Resistance	θја	42.4	°C/W	2s ^(Note 3)
		33.1	°C/W	2s2p ^(Note 4)

(Note 1) The thermal impedance is based on JESD51-2A (Still-Air) standard. It is used the chip of BV2HM050EFV-C (Note 2) JESD51-3 standard FR4 114.3 mm x 76.2 mm x 1.57 mm 1-layer (1s)

(Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.)

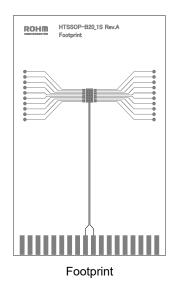
(Note 3) JESD51-5 standard FR4 114.3 mm x 76.2 mm x 1.60 mm 2-layer (2s) (Top copper foil: ROHM recommended Footprint + wiring to measure

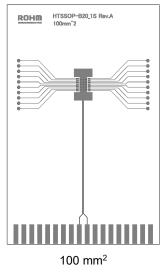
Copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm, copper (top & reverse side) 2 oz.)

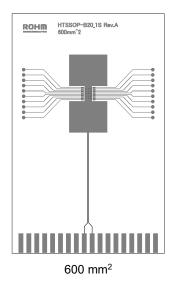
(Note 4) JESD51-5 / -7 standard FR4 114.3 mm x 76.2 mm x 1.60 mm 4-layers (2s2p)

(Top copper foil: ROHM recommended Footprint + wiring to measure
2 inner layers and copper foil area on the reverse side of PCB: 74.2 mm x 74.2 mm, copper (top & reverse side / inner layers) 2 oz / 1 oz.)

PCB Layout 1 layer (1s)







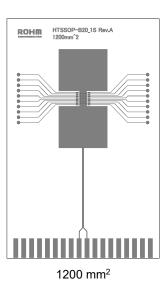


Figure 6. PCB Layout 1 layer (1s)

Dimension	Value
Board finish thickness	1.57 mm
Board dimension	76.2 mm x 114.3 mm
Board material	FR4
Copper thickness	0.070 mm (Cu: 2oz)
Copper foil area	Footprint / 100 mm ² / 600 mm ² / 1200 mm ²

Thermal Resistance - continued

■ PCB Layout 2 layers (2s)

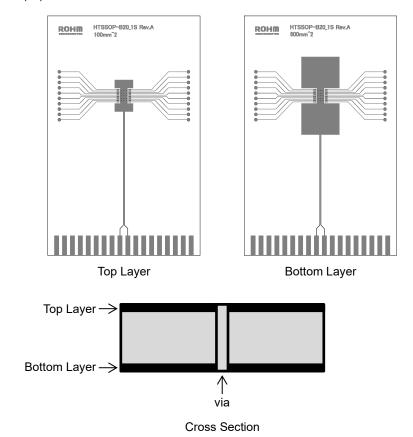


Figure 7. PCB Layout 2 layers (2s)

Dimension	Value
Board finish thickness	1.60 mm
Board dimension	76.2 mm x 114.3 mm
Board material	FR4
Copper thickness (Top / Bottom layers)	0.070 mm (Cu: 1oz + Plating)
Thermal vias separation / diameter	1.2 mm / 0.3 mm

Thermal Resistance - continued

■ PCB Layout 4 layers (2s2p)

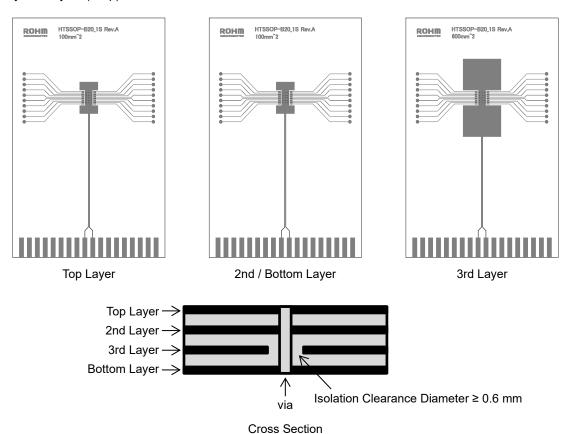


Figure 8. PCB Layout 4 layers (2s2p)

Dimension	Value
Board finish thickness	1.60 mm
Board dimension	76.2 mm x 114.3 mm
Board material	FR4
Copper thickness (Top / Bottom layers)	0.070 mm (Cu: 1oz + Plating)
Copper thickness (Inner layers)	0.035 mm
Thermal vias separation / diameter	1.2 mm / 0.3 mm

Thermal Resistance - continued

■ Transient Thermal Resistance (Single Pulse)

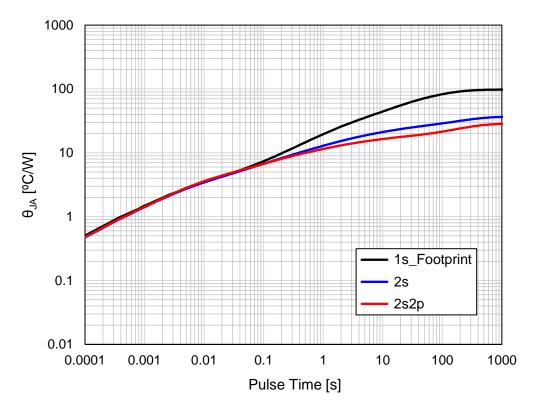


Figure 9. Transient Thermal Resistance

■ Thermal Resistance (θ_{JA} vs Copper foil area- 1s)

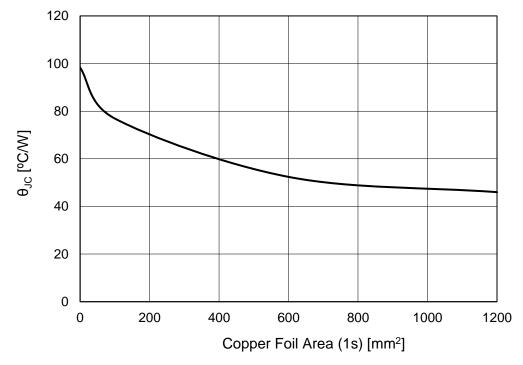


Figure 10. Thermal Resistance

Electrical Characteristics (unless otherwise specified V_{BB} = 6 V to 28 V, Tj = -40 °C to +150 °C)

Parameter	Symbol		Limit	_	Unit	Conditions
raiailietei	Symbol	Min	Тур	Max	UIIIL	Conditions
[Power Supply]			T		T	
Standby Current	I _{BBL1}	1	-	0.5	μA	V _{BB} = 14 V, V _{IN} = 0 V, V _{OUT} = 0 V, Tj = 25 °C
Standby Guirent	I _{BBL2}	-	-	20	μA	V _{BB} = 14 V, V _{IN} = 0 V, V _{OUT} = 0 V, Tj = 150 °C
Operating Current	I _{BBH}	-	5	10	mA	V _{BB} = 14 V, V _{IN} = 5 V, V _{OUT} = Open
UVLO Detection Voltage	Vuvlo	1	-	5.0	V	
UVLO Hysteresis Voltage	V _{UVHYS}	ı	-	1.0	V	
[Input (V _{IN1} , V _{IN2})]						
High Level Input Voltage	VINH	2.1	-	-	V	
Low Level Input Voltage	VINL	-	-	0.9	V	
Input Hysteresis Voltage	V_{HYS}	-	0.3	-	V	
High Level Input Current	I _{INH}	-	50	150	μA	V _{IN} = 5 V
Low Level Input Current	I _{INL}	-10	-	+10	μA	V _{IN} = 0 V
[Power MOS Output]						
	R _{ON1}	-	50	65	mΩ	V _{BB} = 8 V to 18 V, Tj = 25 °C
Output ON Resistance	R _{ON2}	-	-	115	mΩ	V _{BB} = 8 V to 18 V, Tj = 150 °C
	R _{ON3}	-	-	90	mΩ	V _{BB} = 6 V, Tj = 25 °C
Output Look Current	I _{OUTL1}	-	-	0.5	μA	V _{IN} = 0 V, V _{OUT} = 0 V, Tj = 25 °C
Output Leak Current	I _{OUTL2}	-	-	20	μΑ	$V_{IN} = 0 V, V_{OUT} = 0 V, Tj = 150 °$
Output Slew Rate when ON	SRon	0.05	0.20	0.50	V/µs	$V_{BB} = 14 \text{ V}, R_{L} = 6.5 \Omega$
Output Slew Rate when OFF	SRoff	0.05	0.20	0.50	V/µs	$V_{BB} = 14 \text{ V}, R_{L} = 6.5 \Omega$
Output Propagation Delay Time when ON	touton	-	70	160	μs	$V_{BB} = 14 \text{ V}, R_{L} = 6.5 \Omega$
Output Propagation Delay Time when OFF	toutoff	-	70	160	μs	V_{BB} = 14 V, R_{L} = 6.5 Ω
Output Clamp Voltage	V _{DSCLP}	45	50	55	V	$V_{IN} = 0 V$, $I_{OUT} = 10 \text{ mA}$
[Diagnostics]						
Diagnostic Output Low Voltage	V _{STL}	-	-	0.5	V	I _{ST} = 1 mA
Diagnostic Output Leak Current	Istl	-	-	10	μΑ	V _{ST} = 5 V
Diagnostic Output Propagation Delay Time when ON	tston	10	50	100	μs	
Diagnostic Output Propagation Delay Time when OFF	tstoff	125	300	500	μs	
[Protection Circuit]	_		T _	1	T -	
Overcurrent Value	loc	5	8	11	Α	V _{OUT} = 0 V
Overcurrent Detection ON Time	tocon	-	10	40	μs	V _{OUT} = 0 V
Overcurrent Detection OFF Time	tocoff	1.0	2.5	4.0	ms	
Open Load Detection Voltage	Vold	2.0	3.0	4.0	V	
Open Load Detection Sink Current	I _{OLD}	-	20	60	μA	V _{IN} = 0 V, V _{OUT} = 5 V
Thermal Shutdown Detection Temperature (Note 1) Thermal Shutdown Beleese Temperature	T _{TSDDET}	160	185	210	°C	
Thermal Shutdown Release Temperature (Note 1) Thermal Shutdown Hysteresis Temperature	T _{TSDREL}	150	-	-	°C	
(Note 1) Not 100 % tested.	T _{TSDHYS}	-	10	-	°C	

(Note 1) Not 100 % tested.

Typical Performance Curves

(Unless otherwise specified $V_{BB} = 14 \text{ V}$, $V_{IN} = 5 \text{ V}$, $T_j = 25 ^{\circ}\text{C}$)

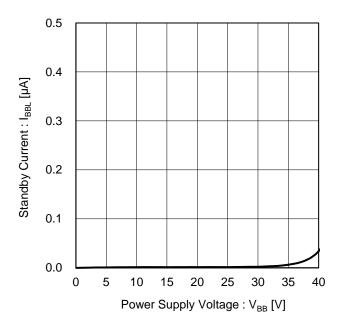
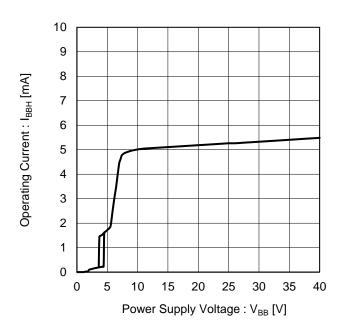


Figure 11. Standby Current vs Power Supply Voltage

Figure 12. Standby Current vs Junction Temperature





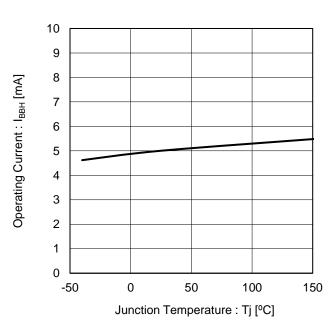
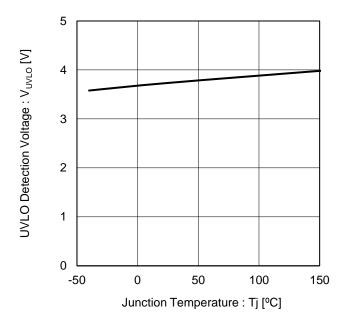


Figure 14. Operating Current vs Junction Temperature



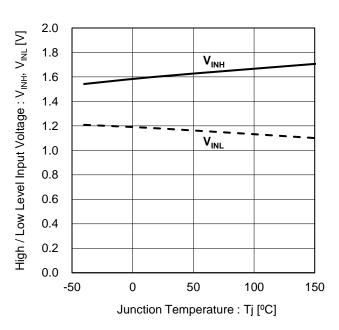
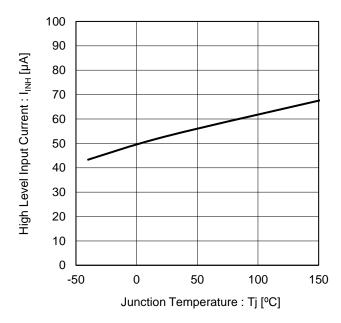


Figure 15. UVLO Detection Voltage vs Junction Temperature

Figure 16. High / Low Level Input Voltage vs Junction Temperature



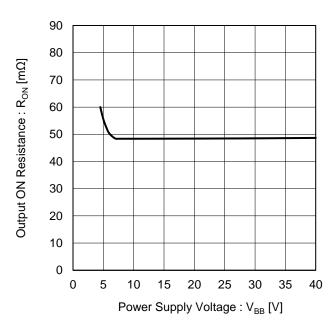
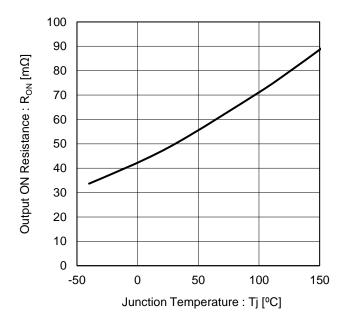


Figure 17. High Level Input Current vs Junction Temperature

Figure 18. Output ON Resistance vs Power Supply Voltage



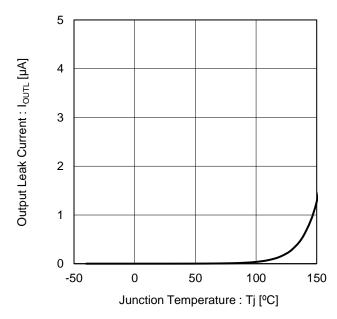


Figure 19. Output ON Resistance vs Junction Temperature

Figure 20. Output Leak Current vs Junction Temperature

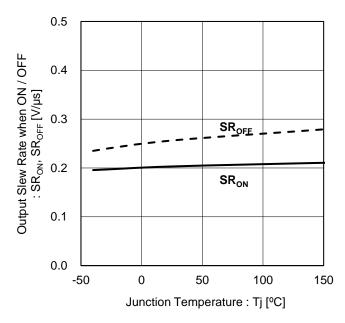


Figure 21. Output Slew Rate when ON / OFF vs Junction Temperature

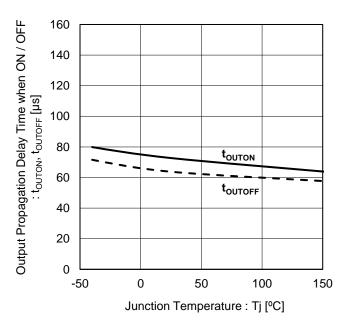
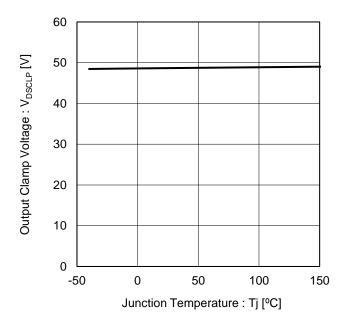


Figure 22. Output Propagation Delay Time when ON / OFF vs Junction Temperature



0.5

| S | LS | 0.4 | 0.4 | 0.2 | 0.0 | 0.2 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 0.

Figure 23. Output Clamp Voltage vs Junction Temperature

Figure 24. Diagnostic Output Low Voltage vs Junction Temperature

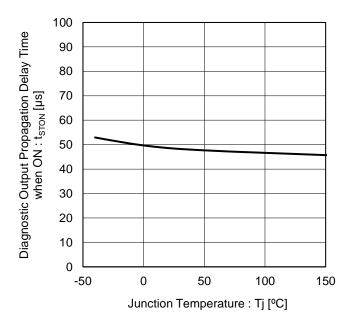


Figure 25. Diagnostic Output Propagation Delay Time when ON vs Junction Temperature

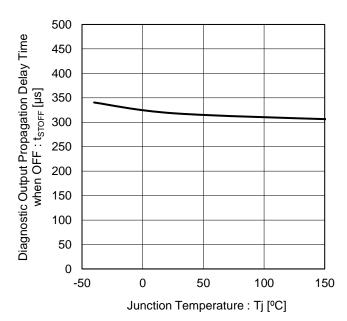
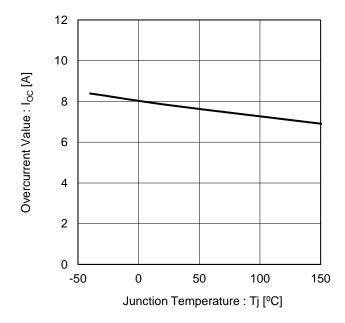


Figure 26. Diagnostic Output Propagation Delay Time when OFF vs Junction Temperature



40 Overcurrent Detection ON Time: tocon [µs] 35 30 25 20 15 10 5 0 0 -50 50 100 150 Junction Temperature : Tj [°C]

Figure 27. Overcurrent Value vs Junction Temperature

Figure 28. Overcurrent Detection ON Time vs Junction Temperature

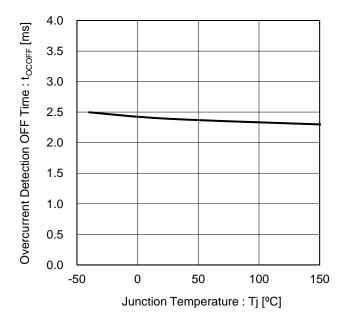


Figure 29. Overcurrent Detection OFF Time vs Junction Temperature

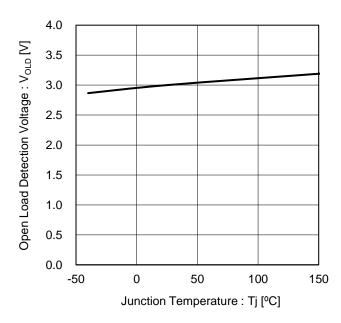


Figure 30. Open Load Detection Voltage vs Junction Temperature

Measurement Circuits

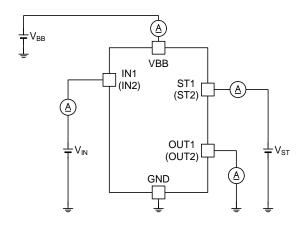


Figure 31. Standby Current
Low Level Input Current
Output Leak Current
Diagnostic Output Leak Current

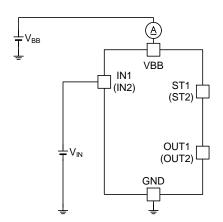


Figure 32. Operating Current

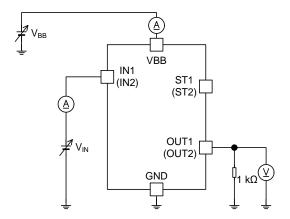


Figure 33. UVLO Detection / Hysteresis Voltage
High / Low Level Input Voltage
Input Hysteresis Voltage
High Level Input Current
Thermal Shutdown Detection
/ Release / Hysteresis Temperature

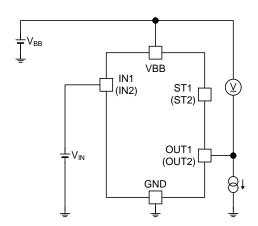


Figure 34. Output ON Resistance Output Clamp Voltage

Measurement Circuits - continued

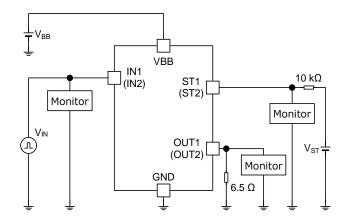


Figure 35. Output Slew Rate when ON / OFF
Output Propagation Delay Time when ON / OFF
Diagnostic Output Propagation Delay Time when ON

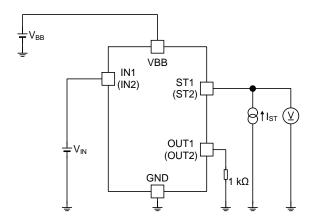


Figure 36. Diagnostic Output Low Voltage

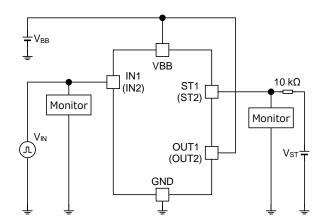


Figure 37. Diagnostic Output Propagation Delay Time when OFF

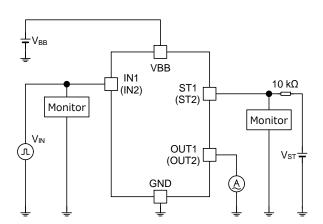


Figure 38. Overcurrent Value
Overcurrent Detection ON / OFF Time

Measurement Circuits - continued

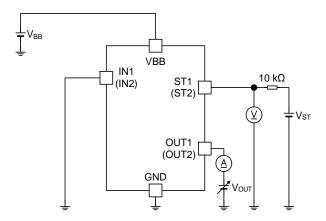


Figure 39. Open Load Detection Voltage Open Load Detection Sink Current

Measurement Conditions for Time Items

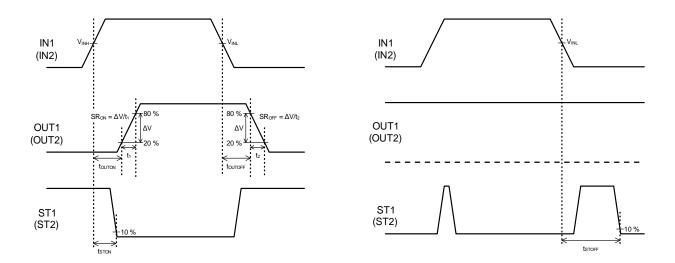


Figure 40. Output Slew Rate when ON / OFF
Output Propagation Delay Time when ON / OFF
Diagnostic Output Propagation Delay Time when ON

Figure 41. Diagnostic Output Propagation Delay Time when OFF

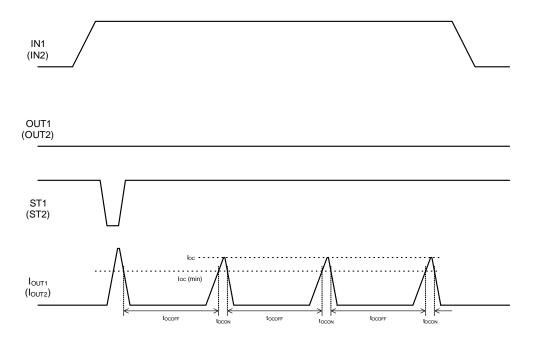


Figure 42. Overcurrent Value
Overcurrent Detection ON / OFF Time

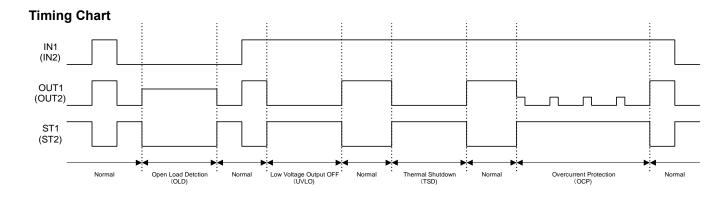


Figure 43. Timing Chart

Description of Blocks

1. Protection Functions

Table 1. Detection and Release Conditions and Diagnostic Output of Each Protection Function(Note 1)

Mode		Detection / Release Conditions	Input Voltage V _{INx}	Diagnostic Output V _{STx}
Normal	Standby	-	Low	High
Condition	Operating	-	High	Low
Open Load De	toot (OLD)	Detect V _{OUTx} ≥ 3.0 V (Typ)	Low	Low
Open Load De	lect (OLD)	Release V _{OUTx} ≤ 2.2 V (Typ)	Low	High
Under Voltage Lockout (UVLO)		Detect V _{BB} ≤ 5.0 V (Max)	High	High
		Release V _{BB} ≥ 6.0 V (Max)	High	Low
Thermal Shutdown Protection		Detect Tj ≥ 185 °C (Typ)	High	High
(TSD) ^(Note 2)		SD) ^(Note 2) Release Tj ≤ 175 °C (Typ) Hi		Low
Overcurrent Protection (OCP)		Detect I _{OUTx} ≥ 6 A (Typ)	High	High
		Release I _{OUTx} < 6 A (Typ)	High	Low

(Note 1) x = 1, 2 and this is the same for x in the following sentence.

(Note 2) Thermal shutdown is automatically restored to normal operation.

This IC has a built-in protection detection function as mentioned above and outputs the condition with diagnostic output pin STx.

In normal condition, when input voltage V_{INx} is switched from Low to High, diagnostic output V_{STx} turns from High to Low. Inversely, when V_{INx} is switched from High to Low, V_{STx} turns from Low to High.

In protection function detected condition, V_{STx} is High when V_{INx} is High, and V_{STx} is Low when V_{INx} is Low. And after detecting protection function, this IC self-restarts and operation becomes normal if above release condition is satisfied.

2. Overcurrent Protection (Output ground fault detection)

This IC has a built-in hiccup mode overcurrent protection function. When the output pin (OUTx) outputs overcurrent, the output of Channel x is turned off and diagnostic output V_{STx} becomes High. After Overcurrent Detection OFF Time (t_{OCOFF}) from turn-off, output self-restarts and operation becomes normal if overcurrent doesn't flow. When overcurrent flows after the self-restart, output is turned off again. So, if the condition that causes overcurrent continues, output repeats ON and OFF periodically. And in this time V_{STx} keeps High.

And output current can exceed Overcurrent Value I_{OC} depending on the condition of impedance connected to VBB, OUT pins.

3. Thermal Shutdown Protection

This IC has a built-in thermal shutdown protection function. When the chip temperature of POWER-MOS unit for Channel x in this IC exceeds 185 °C (Typ), the output of Channel x is turned OFF and diagnostic output V_{STx} becomes High. When the chip temperature of POWER-MOS unit for Channel x goes below 175 °C (Typ), output self-restarts and operation becomes normal.

Description of Blocks - continued 4. Open Load Detection

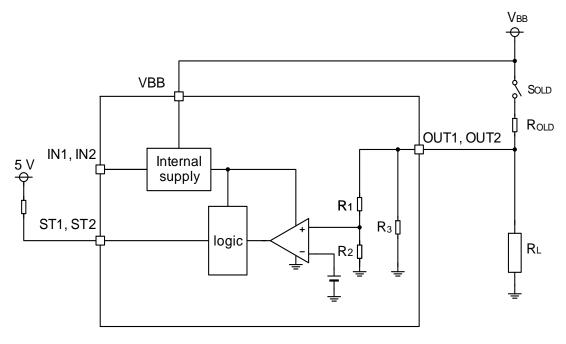


Figure 44. Open Load Detection Block Diagram

This IC has a built-in Open Load Detection function. By connecting an external resistance R_{OLD} between power supply pin (VBB) and output pin (OUTx), when output load (R_L) is disconnected during input voltage V_{INx} is Low, diagnostic output V_{STx} becomes Low.

To reduce the standby current of the system, inserting a switch Sold is recommended.

The value of R_{OLD} is decided based on below formula.

$$\begin{split} R_{OLD} < V_{BBMIN} \times 37.5 \times 10^3 - 150 \times 10^3 ~[\Omega] \\ (= V_{BBMIN} \times \frac{R_{MIN}}{V_{OLDMAX}} - R_{MIN} ~[\Omega] \,) \end{split}$$

Where:

 V_{BBMIN} is the minimum value of power supply voltage (V_{BB}).

 $V_{\rm OLDMAX}$ is the maximum value of Open Load Detection Voltage (V_{OLD}).

 R_{MIN} is the minimum value of combined resistance of internal resistors R₁, R₂ and R₃.

Description of Blocks - continued 5. Other Protection

5.1 GND Open Protection

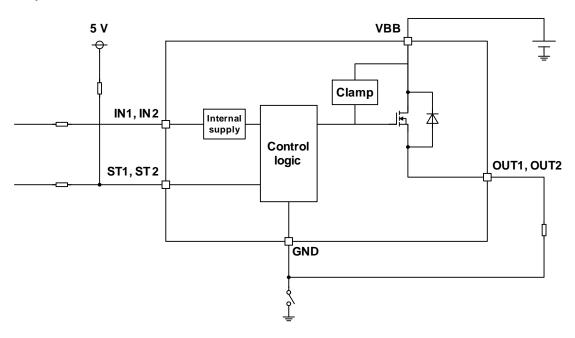


Figure 45. GND Open Protection Block Diagram

When GND of the IC is open, the output is switched OFF regardless of the input voltage V_{INx} . However, diagnostic output V_{STx} is not flagged.

The active clamp operates when GND become open during driving inductive load.

5.2 MCU I/O Protection

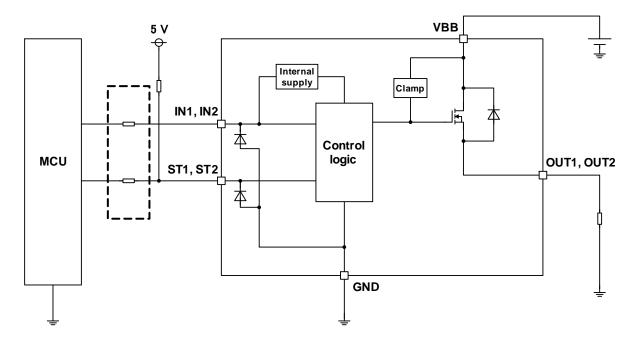
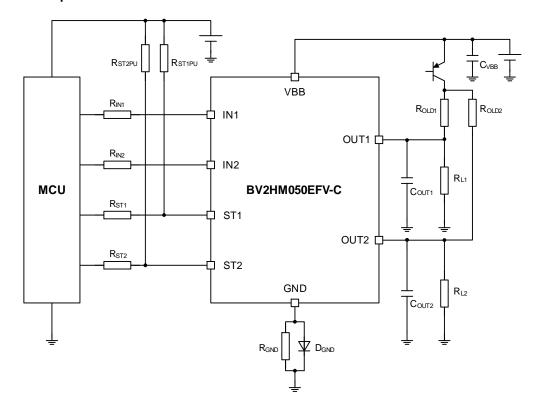


Figure 46. MCU I/O Protection Diagram

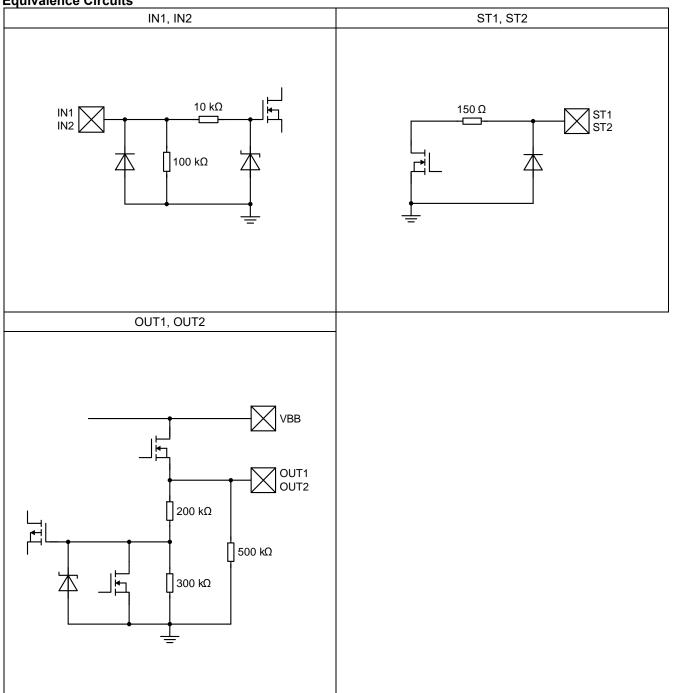
Negative surge voltage to input pin (IN1, IN2) or diagnostic output pin (ST1, ST2) may cause damage to the MCU's I/O pins. In order to prevent those damages, it is recommended to insert limiting resistors between IC pins and MCU.

Applications Example



Symbol	Value	Purpose
R _{IN1} , R _{IN2}	1 kΩ	Limit resistance for negative surge
R _{ST1} , R _{ST2}	1 kΩ	Limit resistance for negative surge
R _{ST1PU} , R _{ST2PU}	10 kΩ	Pull up resistance for diagnostic output The ST1 and ST2 pins are open drain output and pull up these pins to MCU power supply.
Сувв	10 μF	Filter for battery line voltage spike
R _{GND}	1 kΩ	Current limit resistance for reverse battery connection
DGND	-	Protection diode for BV2HM050EFV-C against reverse battery connection
Rold1, Rold2	2 kΩ	Resistance for open load detection
Cout1, Cout2	1000 pF	Filter for radiation noise from outside of BV2HM050EFV-C
R _{L1} , R _{L2}	-	Output load

I/O Equivalence Circuits



Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Except for pins the output and the input of which were designed to go below ground, ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

10. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

11. Thermal Shutdown Function (TSD)

This IC has a built-in thermal shutdown function that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD function that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD function operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD function be used in a set design or for any purpose other than protecting the IC from heat damage.

Operational Notes - continued

12. Over Current Protection Function (OCP)

This IC incorporates an integrated overcurrent protection function that is activated when the load is shorted. This protection function is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection function.

13. Active Clamp Operation

The IC integrates the active clamp function to internally absorb the reverse energy E_L which is generated when the inductive load is turned off. When the active clamp operates, the thermal shutdown function does not work. Decide a load so that the reverse energy E_L is active clamp energy E_{AS} (refer to Figure 5. Active Clamp Energy vs Output Current) or under when inductive load is used.

14. Open Power Supply Pin

When the power supply pin (VBB) becomes open at ON (IN = High), the output is switched to OFF regardless of input voltage. If an inductive load is connected, the active clamp operates when VBB is open and becomes the same potential as that on the ground. At this time, the output voltage drops down to -48 V (Typ).

15. Open GND Pin

When the GND pin becomes open at ON (IN = High), the output is switched to OFF regardless of input voltage. If an inductive load is connected, the active clamp operates when the GND pin is open.

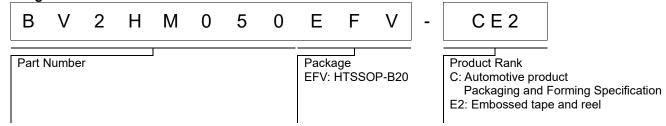
16. OUT Pin Voltage

Ensure that keep OUT pin voltage less than (VBB + 0.3 V) at any time, even during transient condition. And ensure that OUT pin voltage is more than (GND – 0.3 V) when this IC is turned ON. Otherwise malfunction or other problems can occur.

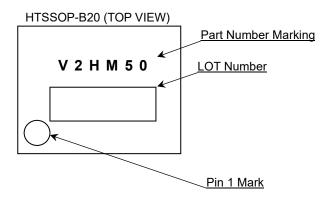
17. Same Pin Connection

Connect all VBB pins, GND pins, OUT1 pins, OUT2 pins to same line respectively.

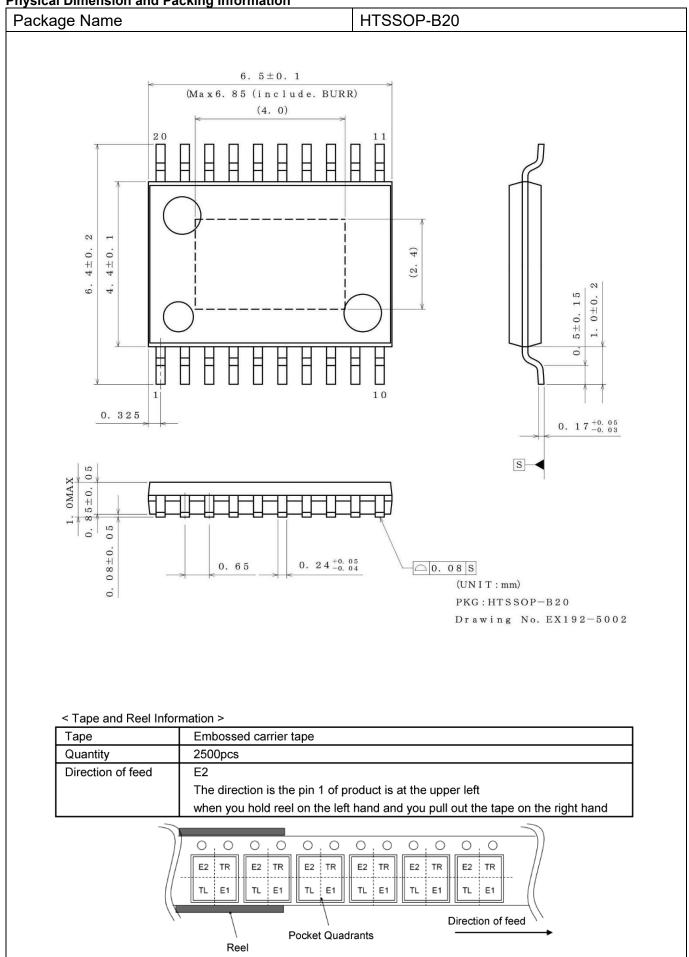
Ordering Information



Marking Diagram



Physical Dimension and Packing Information



Revision History

Date	Revision	Changes
20.Jan.2022	001	New Release
31.Oct.2022	002	Page.27 Ordering Information The Description of "Part Number" is added.

Notice

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ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CLASSIII	CLASS II b	CLASSIII
ſ	CLASSIV		CLASSⅢ	

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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